# TRIPLE DIFFUSED PLANER TYPE HIGH VOLTAGE,HIGH SPEED SWITCHING

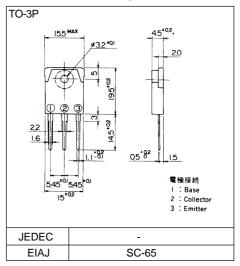
#### ■ Features

- High voltage, High speed switching
- High reliability

## Applications

- Switching regulators
- DC-DC convertor
- Solid state relay
- General purpose power amplifiers

### ■ Outline Drawings



## ■ Maximum ratings and characteristics

#### ● Absolute maximum ratings (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	Vсво	450	V
Collector-Emitter voltage	VCEO	400	V
Collector-Emitter voltage	VCEO(SUS)	400	V
Emitter-Base voltage	Vево	7	V
Collector current	lc	7	Α
Base current	<b>I</b> B	2.0	Α
Collector power disspation	Pc	80	W
Operating junction temperature	Tj	+150	℃
Storage temperature	Tstg	-55 to +150	℃

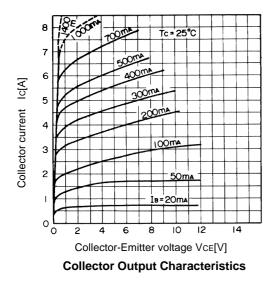
#### ● Electrical characteristics (Tc =25°C unless otherwise specified)

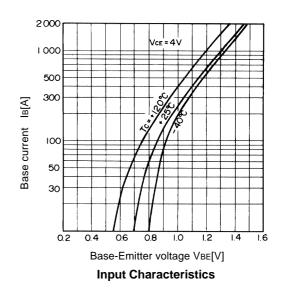
Item	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Collector-Base voltage	Vсво	ICBO = 1mA	450			V
Collector-Emitter voltage	VCEO	ICEO = 10mA	400			V
Collector-Emitter voltage	VCEO(SUS)	Ic = 1A	400	-		V
Emitter-Base voltage	VEBO	IEBO = 0.1mA	7	-		V
Collector-Base leakage current	Ісво	VCBO = 450V		-	1.0	mA
Emitter-Base leakage current	<b>I</b> EBO	VEBO = 7V		-	0.1	mA
D.C. current gain	hfe	IC = 3A, VCE = 4V	10			
Collector-Emitter saturation voltage	VCE(Sat)	IC = 7A, IB = 1.4A			1.5	V
Base-Emitter saturation voltage	VBE(Sat)				1.2	V
*1	ton	IC = 7A, IB1 = -IB2 = 1.4A			1.5	μs
Switching time	<b>t</b> stg	RL = 30 ohm ,Pw = 20µs Duty=<2%			3.0	μs
	tf	,			1.5	μs

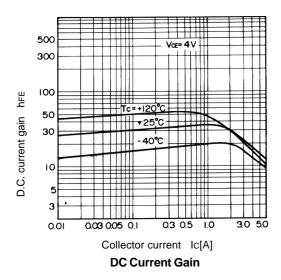
#### Thermal characteristics

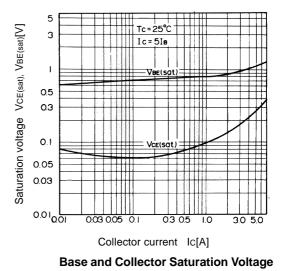
Item	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Thermal resistance	Rth(j-c)	Junction to case			1.5	°C/W

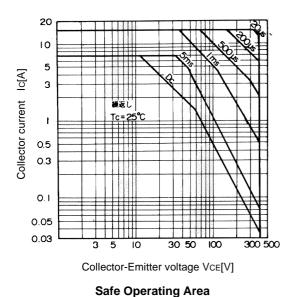
#### Characteristics

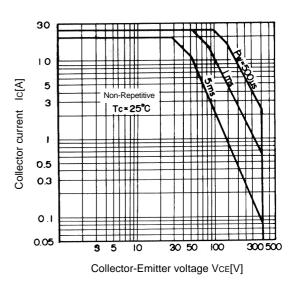






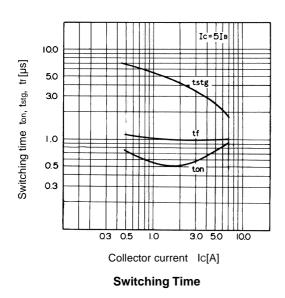






Safe Operating Area

# Characteristics



# \*1 Switching Time Test Circuit

